# imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## VS-12F(R) Series

Vishay Semiconductors



## Standard Recovery Diodes (Stud Version), 12 A



PRODUCT SUMMARY			
I <sub>F(AV)</sub>	12 A		
Package	DO-203AA (DO-4)		
Circuit configuration	Single diode		

#### FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Wide current range

Types up to 1200 V V<sub>RRM</sub>

- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

- Battery charges
- Converters
- Power supplies
- Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		12	А	
I <sub>F(AV)</sub>	T <sub>C</sub>	144	°C	
I <sub>F(RMS)</sub>		19	А	
I <sub>FSM</sub>	50 Hz	265	۸	
	60 Hz	280	A	
l <sup>2</sup> t	50 Hz	351	A <sup>2</sup> s	
	60 Hz	320	A-s	
V <sub>RRM</sub>	Range	100 to 1200	V	
TJ		-65 to +175	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 175 °C mA	
	10	100	150		
	20	200	275		
	40	400	500		
VS-12F(R)	60	600	725	12	
	80	800	950		
	100	1000	1200		
	120	1200	1400		

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### Vishay Semiconductors

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	180° conduction, half sine wave		12	А	
at case temperature	'F(AV)			144	°C	
Maximum RMS forward current	I <sub>F(RMS)</sub>			19	А	
		t = 10 ms	No voltage		265	A
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	280	
non-repetitive surge current	IFSM	t = 10 ms	100 % V <sub>BBM</sub>		225	
		t = 8.3 ms	reapplied		235	
	l <sup>2</sup> t	t = 10 ms	No voltage		351	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		320	
		t = 10 ms	100 % V <sub>BBM</sub>		250	
		t = 8.3 ms	reapplied		226	
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		3510	A²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x I <sub>F(AV)</sub> < I < $\pi$ x I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum			0.77	v
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.97	v
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), T <sub>J</sub> = T <sub>J</sub> maximum			10.70	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J$ maximum 6.20			mΩ	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk} = 38 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s} \text{ rectangular wave}$			1.26	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	ange T <sub>J</sub> -65		-65 to +175	°C
Maximum storage temperature range	T <sub>Stg</sub>		-65 to +200	-0
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2	K/W
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	CS Mounting surface, smooth, flat and greased		r√ vv
		Not lubricated threads	1.5 + 0 - 10 %	N·m
Allowable mounting torque		Not lubricated threads	13	lbf ∙ in
Allowable mounting torque	Lub	Lubricated threads	1.2 + 0 - 10 %	N⋅m
		Lubricated threads	10	lbf ∙ in
Approvimate weight			7	g
Approximate weight			0.25	oz.
Case style		See dimensions - link at the end of datasheet DO-203AA (DO-4		A (DO-4)

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.33	0.26			
120°	0.41	0.44			
90°	0.53	0.58	$T_J = T_J maximum$	K/W	
60°	0.78	0.81			
30°	1.28	1.29			

Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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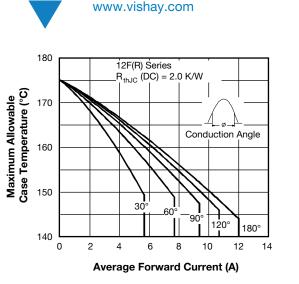


Fig. 1 - Current Ratings Characteristics

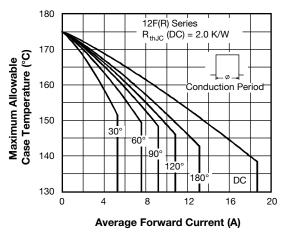


Fig. 2 - Current Ratings Characteristics

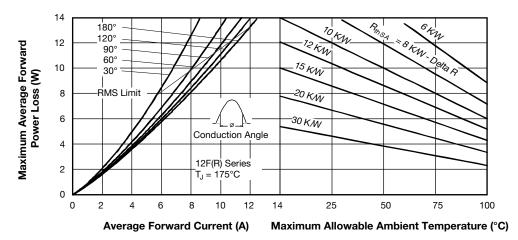
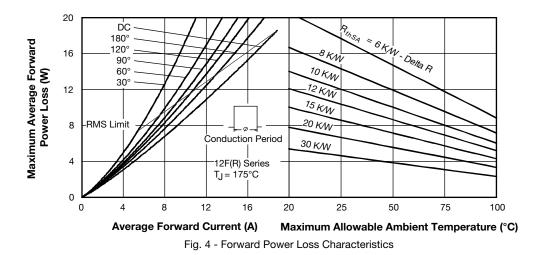
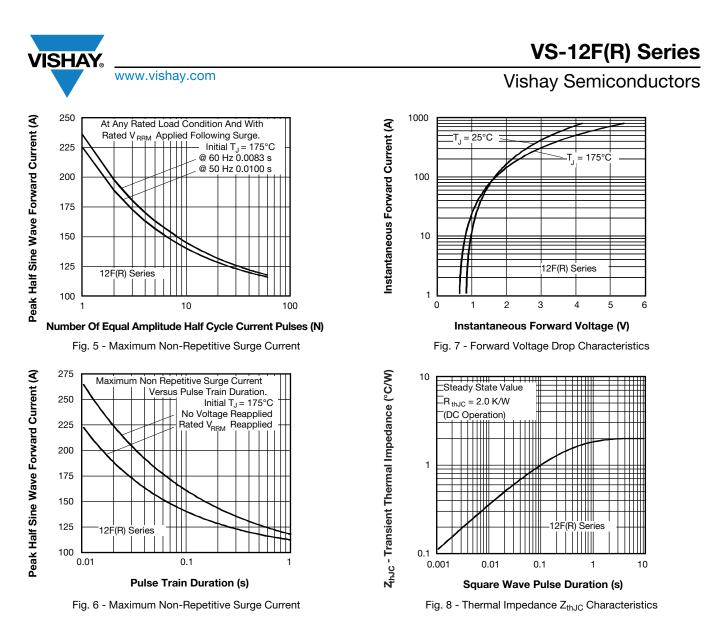
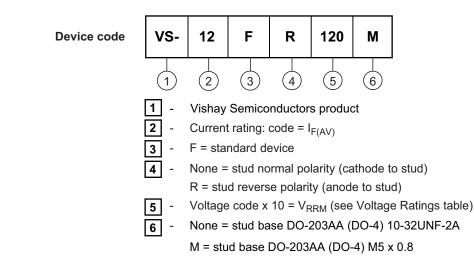


Fig. 3 - Forward Power Loss Characteristics





#### **ORDERING INFORMATION TABLE**



LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95311					
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R 0.40 R (0.02)

Ø 6.8 (0.27)

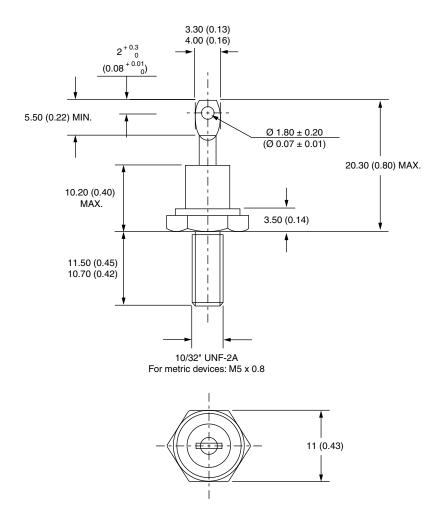
 $0.8 \pm 0.1$ 

 $(0.03 \pm 0.004)$ 



## DO-203AA (DO-4)

#### **DIMENSIONS** in millimeters (inches)





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